AUTOMOTIVE

Available

COMPLIANT

HALOGEN FREE

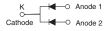


# Vishay General Semiconductor

# **High Current Density Surface Mount Schottky Barrier Rectifier**



### **TO-277A (SMPC)**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 6.0 A			
V <sub>RRM</sub>	40 V			
I <sub>FSM</sub>	150 A			
E <sub>AS</sub>	20 mJ			
V <sub>F</sub> at I <sub>F</sub> = 6.0 A	0.40 V			
T <sub>J</sub> max.	125 °C			

### TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, DC/DC converters and polarity protection applications.

### **FEATURES**

- Very low profile typical height of 1.1 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency
- · Low thermal impedance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- · AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

### **MECHANICAL DATA**

Case: TO-277A (SMPC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and automotive grade

Terminals: Matte tin plated leads, solderable J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	SS12P4C	UNIT
Device marking code			S124C	
Maximum repetitive peak reverse voltage		$V_{RRM}$	40	V
Maximum average forward rectified current (fig. 1) <sup>(1)</sup>	total device		12	А
	per diode	I <sub>F(AV)</sub>	6.0	
Maximum average forward rectified current (2) total device		I <sub>F(AV)</sub>	3.5	А
Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	150	А
Non-repetitive avalanche energy at $T_J = 25$ °C, L = 60 mH per diode		E <sub>AS</sub>	20	mJ
Peak repetitive reverse current at $t_p$ = 2 $\mu$ s, 1 kHz, at $T_J$ = 25 °C per diode		I <sub>RRM</sub>	1.0	А
Operating junction and storage temperature range		T <sub>J,</sub> T <sub>STG</sub>	- 55 to + 125	°C

(1) Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink

(2) Free air, mounted on recommended copper pad area

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 1 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.34	-	. V
	I <sub>F</sub> = 3 A			0.40	-	
	I <sub>F</sub> = 6 A			0.46	0.52	
	I <sub>F</sub> = 1 A	T <sub>A</sub> = 100 °C		0.24	-	
	I <sub>F</sub> = 3 A			0.31	-	
	I <sub>F</sub> = 6 A			0.40	0.45	
Reverse current per diode	Data d.V	T <sub>A</sub> = 25 °C T <sub>A</sub> = 100 °C	1 (2)	129	500	μΑ
	Rated V <sub>R</sub>		I <sub>R</sub> <sup>(2)</sup>	11.9	25	mA
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	400	-	pF

#### Notes

(3) Pulse test: 300 µs pulse width, 1 % duty cycle

(4) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	SS12P4C	UNIT	
Typical thermal resistance	R <sub>0JA</sub> (1)	100	°C/W	
	R <sub>θJM</sub> <sup>(2)</sup>	3		

#### **Notes**

 $^{(1)}$  Free air, mounted on recommended copper pad area. Thermal resistance  $R_{\theta JA}$  - junction to ambient.

(2) Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink. Thermal resistance R<sub>θJM</sub> - junction to mount.

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
SS12P4C-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel	
SS12P4C-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel	
SS12P4CHM3/86A (1)	0.10	86A	1500	7" diameter plastic tape and reel	
SS12P4CHM3/87A (1)	0.10	87A	6500	13" diameter plastic tape and reel	

### Note

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

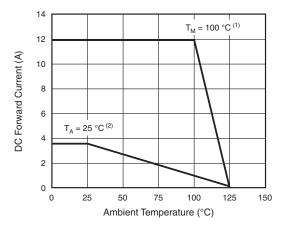


Fig. 1 - Maximum Forward Current Derating Curve

### **Notes**

- Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink,  $T_{\mbox{\scriptsize M}}$  measured at the terminal of cathode band ( $R_{\theta JM} = 3 \, ^{\circ}C/W$ )
- Free air, mounted on recommended copper pad area (R $_{\theta JA} = 100~^{\circ}\text{C/W})$

<sup>(1)</sup> Automotive grade



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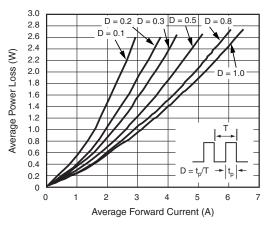


Fig. 2 - Forward Power Loss Characteristics Per Diode

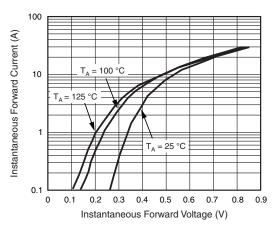


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

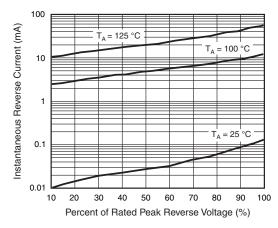


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

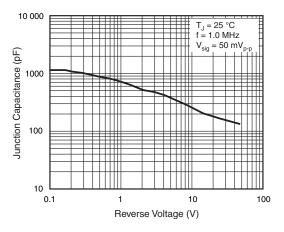


Fig. 5 - Typical Junction Capacitance Per Diode

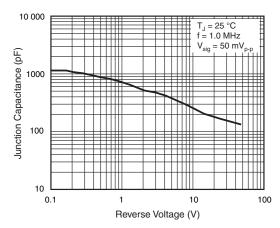


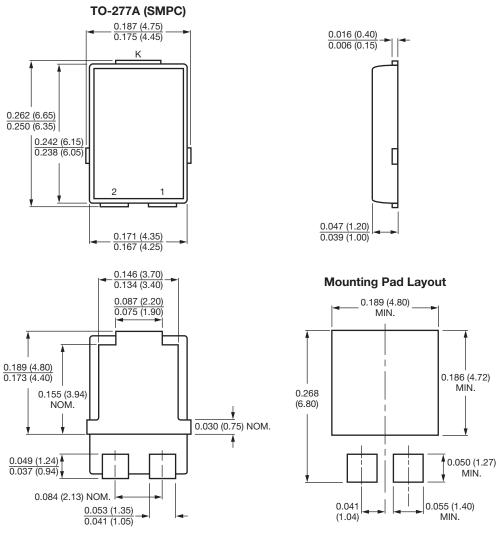
Fig. 6 - Typical Transient IThermal mpedance Per Diode

# SS12P4C

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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)







Vishay

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